VS-VSKDU162/12PbF

Vishay Semiconductors



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HEXFRED[®] Ultrafast Diodes, 100 A (New INT-A-PAK Power Modules)



PRODUCT SUMMARY					
V _R	1200 V				
V _F (typical)	2.5 V				
t _{rr} (typical)	150 ns				
I _{F(DC)} at T _C	110 A at 100 °C				
Package	INT-A-PAK				
Circuit	Two diodes doubler circuit				

FEATURES

- Electrically isolated: DBC base plate
- Standard JEDEC[®] package
- · Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Case style New INT-A-PAK
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V _R		1200	V		
Continuous forward current	$T_{\rm C} = 25 ^{\circ}{\rm C}$		205			
Continuous forward current		T _C = 100 °C	110	А		
Single pulse forward current	I _{FSM}	Limited by junction temperature	800			
Maximum power dissipation P _D		T _C = 25 °C	695	W		
		T _C = 100 °C	280	vv		
RMS isolation voltage	VISOL	50 Hz, circuit to base, all terminal shorted, t = 1 s	3500	V		
Operating junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C		

ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-		
Maximum forward voltage	V _{FM}	I _F = 100 A	-	2.5	3.2	V	
		I _F = 160 A	-	2.9	3.9		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C, V _R = 1200 V	-	18	30	mA	

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COMPLIANT

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	150	200	ns
Reverse recovery current	I _{RRM}	T _J = 25 °C	I _F = 160 A	-	20	22	А
Reverse recovery charge	Q _{rr}	T _J = 25 °C	dl _F /dt = 200 A/µs V _B = 200 V	-	2000	2400	nC
Peak rate of recovery current	dl _{(rec)M} /dt	T _J = 25 °C		-	-	300	A∕µs

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Junction operating and storage temperature range		T _J , T _{Stg}		-40 to +150	°C	
Maximum internal thermal r junction to case per leg	esistance,	R _{thJC} DC operation		0.18	°C/W	
Typical thermal resistance, case to heatsink per modul	e	R _{thCS}	Mounting surface flat, smooth and greased	0.05	C/W	
Mounting torque + 10.9/	to heatsink		A mounting compound is recommended and the		Nim	
Mounting torque ± 10 % -	busbar		torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	6	Nm	
Approximate weight				200	g	
				7.1	oz.	
Case style				New INT	-A-PAK	

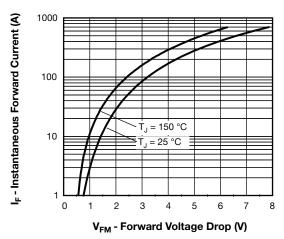


Fig. 1 - Maximum Forward Voltage Drop Characteristics

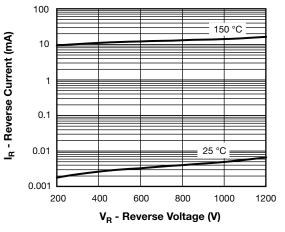


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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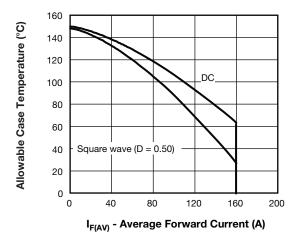


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

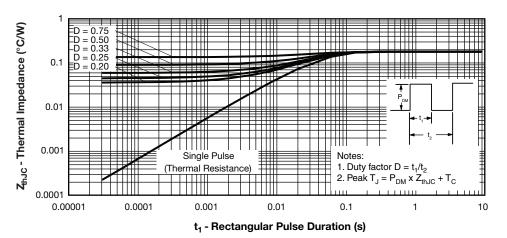


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

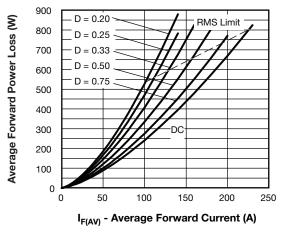
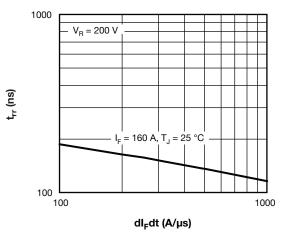
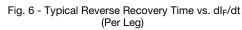


Fig. 5 - Forward Power Loss Characteristics





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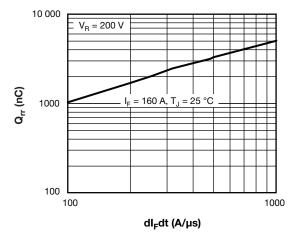


Fig. 7 - Typical Reverse Recovery Charge vs. dl_F/dt (Per Leg)

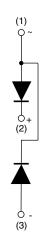
$(\mathbf{f}_{1}) = (\mathbf{f}_{1}) + (\mathbf{f}_{1}) + (\mathbf{f}_{2}) + (\mathbf{$

Fig. 8 - Typical Reverse Recovery Current vs. dl_F/dt (Per Leg)

ORDERING INFORMATION TABLE

Device code	vs-vs	KD	U	162	12	PbF
		2	3	4	5	6
	1 - 2 - 3 - 4 - 5 - 6 -	Circ U = Cur Volt	nay Sem cuit confi HEXFR rent ratii tage ratii	guratior ED [®] ultr ng ng (12 =	rafast di 1200 V	iode

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS					
Dimensions	nensions <u>www.vishay.com/doc?95254</u>				
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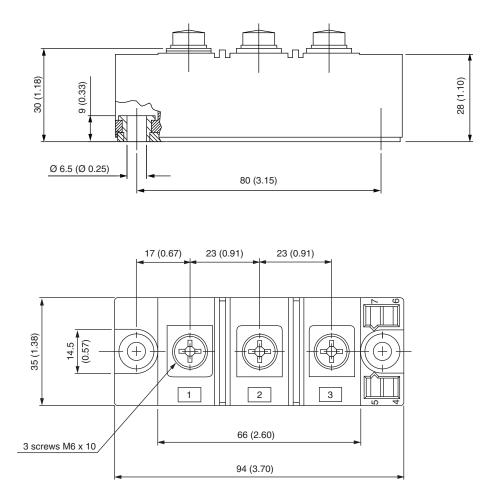


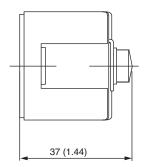
Outline Dimensions

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INT-A-PAK DBC

DIMENSIONS in millimeters (inches)







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